

RG2GE

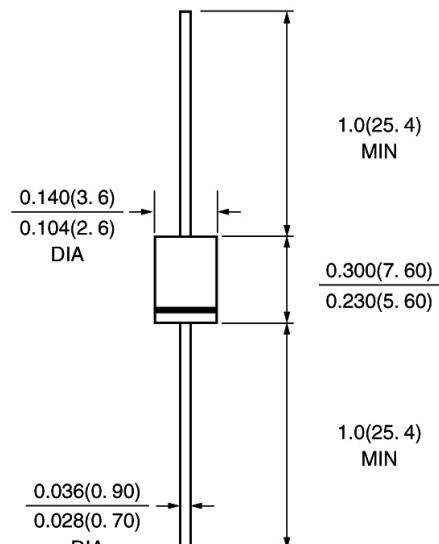
**ULTRAFAST EFFICIENT
PLASTIC SILICON RECTIFIER**
VOLTAGE: 50 TO 1000V **CURRENT: 2.0A**

**FEATURE**

Low power loss
 High surge capability
 Glass passivated chip junction
 Ultra-fast recovery time for high efficiency
 High temperature soldering guaranteed
 250°C/10sec/0.375" lead length at 5 lbs tension

MECHANICAL DATA

Terminal: Plated axial leads solderable per
 MIL-STD 202E, method 208C
 Case: Molded with UL-94 Class V-0 recognized Flame
 Retardant Epoxy
 Polarity: color band denotes cathode
 Mounting position: any

DO-15/DO-204AC

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated)

| | SYMBOL | RG2GE | units |
|---|---------|--------------|------------|
| Maximum Recurrent Peak Reverse Voltage | Vrrm | 400 | V |
| Maximum RMS Voltage | Vrms | 280 | V |
| Maximum DC blocking Voltage | Vdc | 400 | V |
| Maximum Average Forward Rectified Current 3/8" lead length at Ta =60°C | If(av) | 1.2 | A |
| Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load | Ifsm | 50.0 | A |
| Maximum Forward Voltage at Forward current 1.5A | Vf | 1.14 | V |
| Maximum DC Reverse Current Ta =25°C at rated DC blocking voltage Ta =125°C | Ir | 5.0 100.0 | µ A µ A |
| Maximum Reverse Recovery Time (Note 1) | Trr | 35 | nS |
| Typical Junction Capacitance (Note 2) | Cj | 50 | pF |
| Typical Thermal Resistance (Note 3) | R(ja) | 25.0 | °C/W |
| Storage and Operating Junction Temperature | Tstg,Tj | -55 to +150 | °C |

Note:

1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Thermal Resistance from Junction to Ambient at 3/8" lead length, P.C. Board Mounted

